



### **IRG8CH106K10F Information**

Heisener.com

Part Number IRG8CH106K10F

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

**Description** IGBT 1200V 110A DIE

Package Die

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com

E-mail: salesdept@heisener.com



Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









# **IRG8CH106K10F Specifications**

Manufacturer Part Number	IRG8CH106K10F
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	-
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	-
Current - Collector Pulsed (Icm)	-
Vce(on) (Max) @ Vge, Ic	2V @ 15V, 110A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	700nC
Td (on/off) @ 25°C	80ns/380ns
Test Condition	600V, 110A, 1 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-40°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die
	Report errors?

#### IRG8CH106K10F Guarantees



#### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

## **IRG8CH106K10F Payment Methods**



















# IRG8CH106K10F Shipping Methods













If you have any question about IRG8CH106K10F, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com